

# BGA715L7

Silicon Germanium GPS Low Noise Amplifier

Small Signal Discretes



Never stop thinking

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**Revision History: 2009-10-9, Rev.2.1**

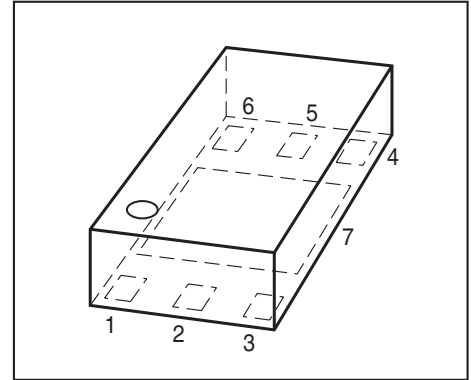
**Previous Version: 2008-09-12, Rev.2.0**

## Data Sheet

## 1 Silicon Germanium GPS Low Noise Amplifier

### Features

- High gain: 20 dB
- Low Noise Figure: 0.7 dB
- Low current consumption: 3.3 mA
- Supply voltage: 1.5 V to 3.3 V
- High input compression point -15.5 dBm at 1.8 V supply
- High input 3rd intercept point -7 dBm at 1.8 V supply
- B7HFM Silicon Germanium technology
- RF output internally matched to 50  $\Omega$
- Low external part count
- 2kV HBM ESD protection (including AI-pin)
- Tiny TSLP-7-1 leadless package
- Moisture sensitivity level: MSL 1
- Pb-free (RoHS compliant) package



TSLP-7-1



### Application

- 1575 MHz GPS, Galileo, GPS phone

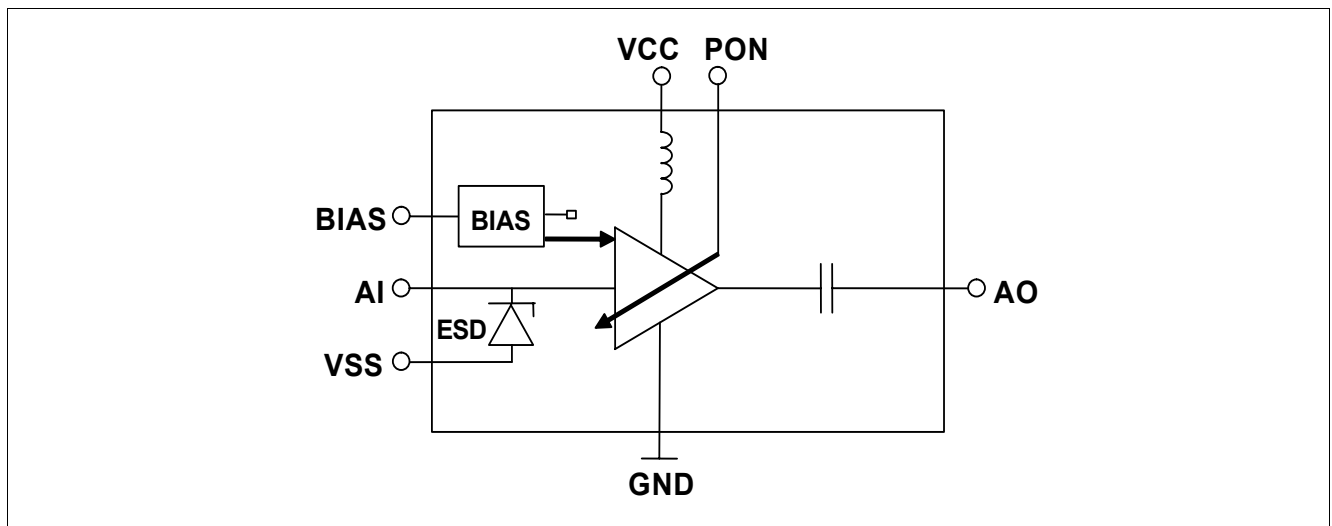


Figure 1 Blockdiagram

## 2 Description

The BGA715L7 is a front-end low noise amplifier for Global Positioning System (GPS) applications. The LNA provides 20 dB gain, 0.7 dB noise figure and high linearity performance in the application configuration described in [Chapter 4](#). Current consumption is as low as 3.3 mA. The BGA715L7 is based upon Infineon Technologies' B7HFM Silicon Germanium technology. It operates over a 1.5 V to 3.3 V supply range.

If an ultra low noise figure of 0.6 dB is required, please refer to Infineon BGA715L7 Application Note AN161.

| Type     | Package  | Marking |
|----------|----------|---------|
| BGA715L7 | TSLP-7-1 | UG      |

## Pin Definition and Function

**Table 1 Pin Definition and Function**

| Pin No. | Symbol | Function         |
|---------|--------|------------------|
| 1       | AI     | LNA input        |
| 2       | BIAS   | DC bias          |
| 3       | GND    | RF ground        |
| 4       | PON    | Power on control |
| 5       | VCC    | DC supply        |
| 6       | AO     | LNA output       |
| 7       | VSS    | DC ground        |

## Maximum Ratings

**Table 2 Maximum Ratings**

| Parameter <sup>1)</sup>   | Symbol         | Value                   | Unit |
|---|----------------|-------------------------|------|
| Voltage at pin VCC  | $V_{CC}$       | -0.3 ... 3.6            | V    |
| Voltage at pin AI   | $V_{AI}$       | -0.3 ... 0.9            | V    |
| Voltage at pin BIAS   | $V_{BIAS}$     | -0.3 ... 0.9            | V    |
| Voltage at pin AO   | $V_{AO}$       | -0.3 ... $V_{CC} + 0.3$ | V    |
| Voltage at pin PON  | $V_{PON}$      | -0.3 ... $V_{CC} + 0.3$ | V    |
| Voltage at pin GND  | $V_{GND}$      | -0.3 ... 0.3            | V    |
| Current into pin VCC  | $I_{CC}$       | 10                      | mA   |
| RF input power  | $P_{IN}$       | 10                      | dBm  |
| Total power dissipation   | $P_{tot}$      | 36                      | mW   |
| Junction temperature  | $T_J$          | 150                     | °C   |
| Ambient temperature range   | $T_A$          | -40 ... 85              | °C   |
| Storage temperature range   | $T_{STG}$      | -65 ... 150             | °C   |
| <sup>2)</sup> Human Body Model ESD capability, all pin to all pin | $V_{ESD\_HBM}$ | 2000                    | V    |
| <sup>3)</sup> Machine Model ESD capability, all pin to all pin    | $V_{ESD\_MM}$  | 100                     | V    |

1) All voltages refer to VSS-Node.

2) According to JEDEC22A-114

3) According to JEDEC22A-115

## Thermal resistance

**Table 3 Thermal resistance**

| Parameter                                | Symbol     | Value | Unit |
|--|------------|-------|------|
| Junction - soldering point <sup>1)</sup> | $R_{thJS}$ | 159   | K/W  |

1) For calculation of  $R_{thJA}$  please refer to Application Note Thermal Resistance

### 3 Electrical Characteristics

**Table 4** Electrical Characteristics<sup>1)</sup>:  $T_A = 25\text{ °C}$ ,  $V_{CC} = 1.8\text{ V}$ ,  $V_{PON,ON} = 1.8\text{ V}$ ,  $V_{PON,OFF} = 0\text{ V}$ ,  
 $f = 1575\text{ MHz}$

| Parameter  | Symbol         | Values |       |      | Unit | Note / Test Condition                                   |
|--|----------------|--------|-------|------|------|---|
|  |                | Min.   | Typ.  | Max. |      |   |
| Supply voltage                                       | $V_{CC}$       | 1.5    | 1.8   | 3.6  | V    |   |
| Supply current                                       | $I_{CC}$       | -      | 3.3   | -    | mA   | ON-mode   |
|  |                | -      | 0.2   | 3    | μA   | OFF-mode  |
| Gain switch control voltage                          | $V_{pon}$      | 1.0    | -     | Vcc  | V    | ON-mode   |
|  |                | 0      | -     | 0.4  | V    | OFF-mode  |
| Gain switch control current                          | $I_{pon}$      | -      | 5     | -    | μA   | ON-mode   |
|  |                | -      | -     | 1    | μA   | OFF-mode  |
| Power gain   | $ S_{21} ^2$   | -      | 20    | -    | dB   | High-gain Mode  |
| Noise figure <sup>2)</sup>                           | $NF$           | -      | 0.7   | -    | dB   | $Z_S = 50\text{ }\Omega$                                |
| Input return loss                                    | $RL_{in}$      | -      | 14    | -    | dB   |   |
| Output return loss                                   | $RL_{out}$     | -      | 13    | -    | dB   |   |
| Reverse isolation                                    | $1/ S_{12} ^2$ | -      | 43    | -    | dB   |   |
| Power gain settling time <sup>3)</sup>               | $t_S$          | -      | 5     | -    | μs   | OFF- to ON-mode   |
|  |                | -      | 5     | -    | μs   | ON- to OFF-mode   |
| Inband input 1dB compression point                   | $IP_{1dB}$     | -      | -15.5 | -    | dBm  |   |
| Inband input 3rd order intercept point <sup>4)</sup> | $IIP_3$        | -      | -7    | -    | dBm  | $f_1 = 1575\text{ MHz}$<br>$f_2 = f_1 \pm 1\text{ MHz}$ |
| Stability  | $k$            | -      | > 1   | -    |      | $f = 20\text{ MHz} \dots 20\text{ GHz}$                 |

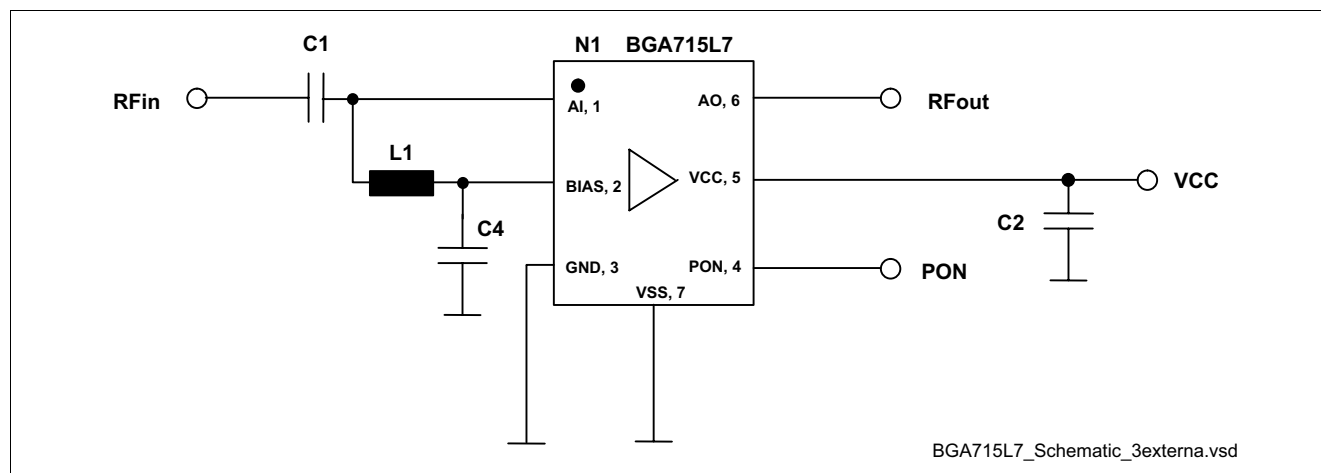
1) Measured on BGA715L7 application board according to application schematic on page 7, including PCB losses (unless noted otherwise)

2) PCB transmission line- and connector losses of 0.05dB are subtracted

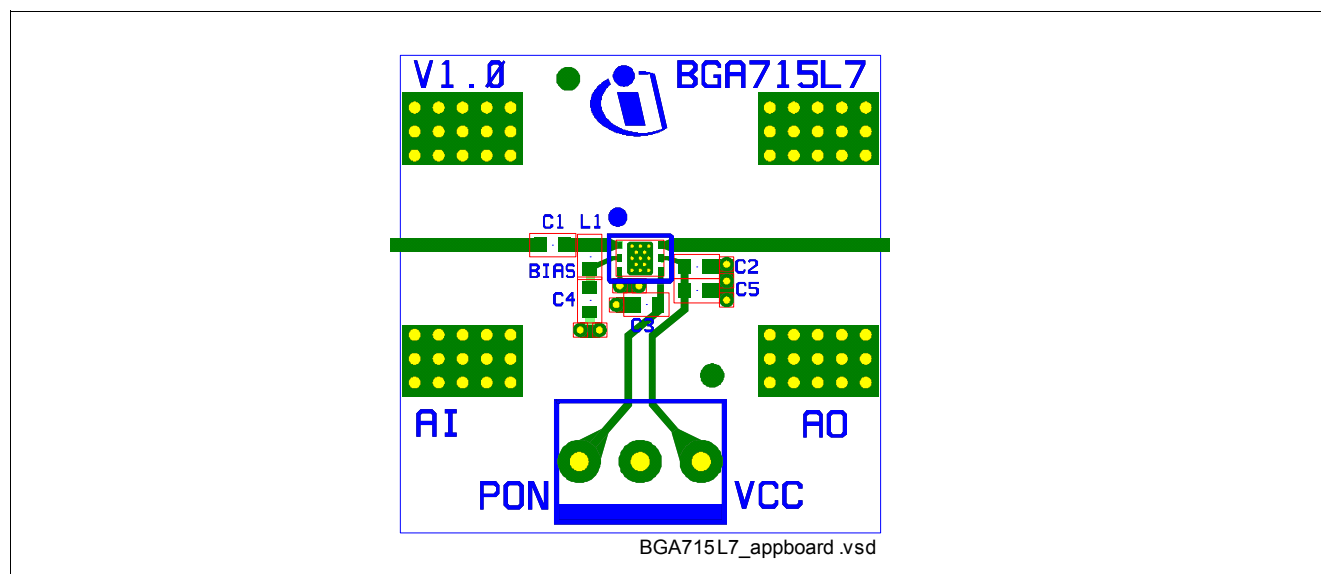
3) To be within 1 dB of the final gain OFF- to ON-mode; to be within 3 dB of the final gain ON- to OFF-mode

4) Input Power = -30 dBm for each tone

## 4 Application Information



**Figure 2** Application Schematic BGA715L7



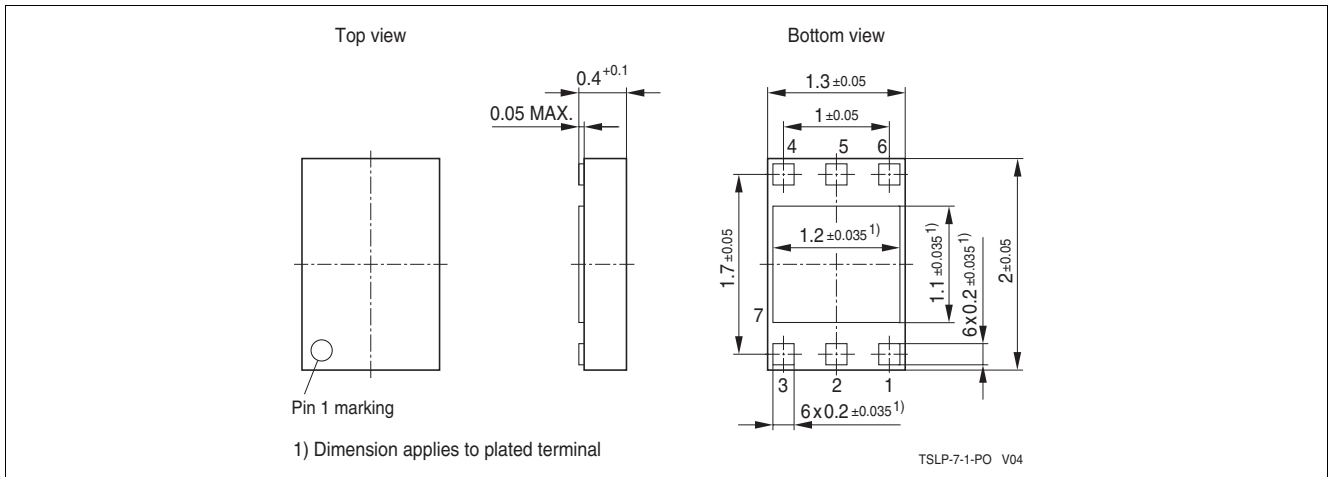
**Figure 3** Application Board Drawing BGA715L7

**Table 5** Bill of Materials

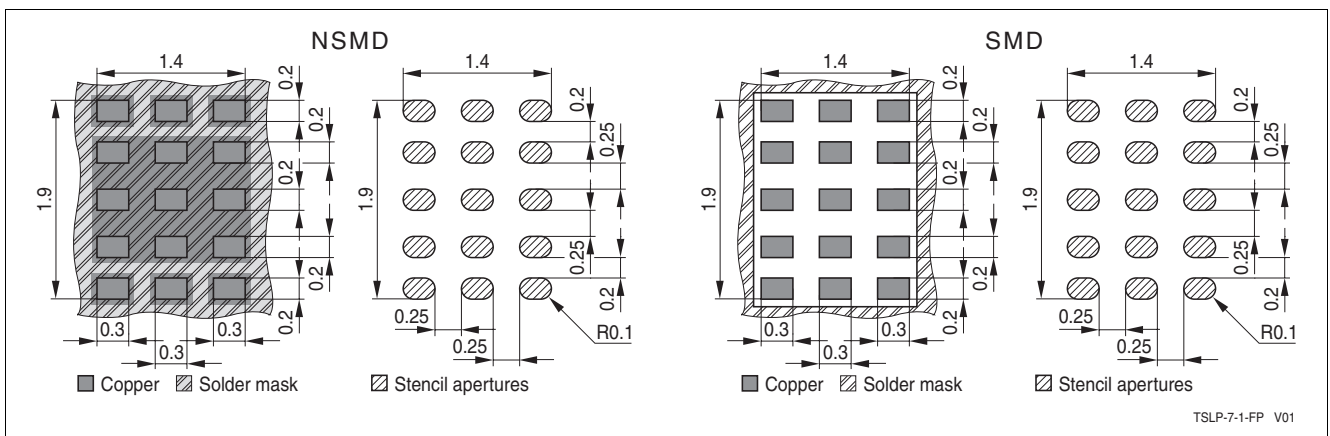
| Name | Value                   | Package  | Manufacturer | Function                       |
|------|-------------------------|----------|--------------|--------------------------------|
| C1   | 1.8 pF                  | 0402     | Various      | DC blocking and input matching |
| C2   | 1 $\mu$ F               | 0402     | Various      | RF block                       |
| C4   | 15 pF                   | 0402     | Various      | RF block                       |
| L1   | 4.7 nH<br>LQW15A series | 0402     | Murata       | Bias feed and input matching   |
| N1   | BGA715L7                | TSLP-7-1 | Infineon     | SiGe LNA                       |

A list of all application notes is available at <http://goto.infineon.com/smallsignaldiscretes-appnotes>.

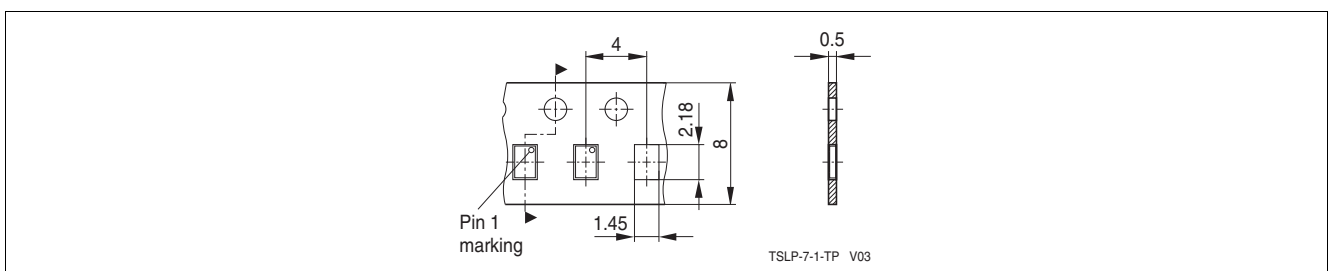
## 5 Package Information



**Figure 4 Package Dimensions for TSLP-7-1**



**Figure 5 Footprint TSLP-7-1**



**Figure 6 Tape & Reel Dimensions (Ø reel 180, pieces/reel 7500)**